TRANSMITTAL OF INFORMATION DISCLOSURE STATEM (Under 37 CFR 1.97(b) or 1.97(c))	Docket No. Q175-US1						
In Re Application Of: Taison Tan et al. MAR 0 2 2004							
Serial No. Filing Date Exam 10/718,981 November 24, 2003 N/A							
Title: PRIMARY BATTERY HAVING SLOPED VOLTAGE DECAY							
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Address to: Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450							
37 CFR 1.97(b)							
1. A The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.							
37 CFR 1.97(c)							
CFR 1.97(b), provided that the Information Disclosure Statement is Final Action under 37 CFR 1.113, a Notice of Allowance under	2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:						
☐ the statement specified in 37 CFR 1.97(e);							
OR							
☐ the fee set forth in 37 CFR 1.17(p).							
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	SURE STATEMENT (c))	Docket No. Q175-US1		
In Re Application: T	aison Tan et al. MAR 0 2			
Serial No.	Filing Date	Examiner	Group Art Unit	
10/718,981	Filing Date November 24, 2003	EMBL N/A	1745	
PRIMARY BATT	ERY HAVING SLOPED VOLTAC	GE DECAY		
	•	ent of Fee ts to pay the fee set forth in 37 CFR 1		
as described belo Charge th Credit any Charge at Certificate of T	re amount of y overpayment. ny additional fee required. Fransmission by Facsimile* ent and authorization to charge deposit nile transmitted to the United States	Certificate of Mailing by	fee is being deposited the U.S. Postal Service C.F.R. 1.8 and is or for Patents, P.O. Box	
	Signature	Signature of Person Mailing Correspondence		
Typed or Printed N	ame of Person Signing Certificate	Typed or Printed Name of Person Mailing Certificate		
- 1 /2r	y only be used if paying by	Dated: 2-26-04		



INFORMATION DISCLOSURE STATEMENT BY APPLICANT

of

Application Number	10/718,981
Filing Date	November 20, 2003
First Named Inventor	Taison Tan et al.
Art Unit	1745
Examiner Name	N/A
Attorney Docket number	Q175-US1

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Signature	-	Considered	

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Signature

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Date

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